NSN 5962-01-087-9498

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Body Length:	
0.785 inches	
Body Width:	
0.291 inches	
Body Height:	
Between 0.145 inches and 0.195 inches	
Maximum Power Dissipation Rating:	
210.0 milliwatts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
End Application:	
Teletypewriter set, type an/ugc-7 ()(v)	
Features Provided:	
Hermetically sealed and monolithic and positive outputs and w/storage and programmable and programmed and bipolar and schottky and	
w/enable and 3-state output	
Inclosure Material:	
Ceramic and glass	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
10 input	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic:	
5.5 volts power source	
Time Rating Per Chacteristic:	
60.00 nanoseconds propagation delay time, low to high level output and 60.00 nanoseconds propagation delay time, high to low level	
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Test Data Document:	
80063-sm-a-915597 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,	
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)	
Terminal Type And Quantity:	

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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